

Si PIN photodiode

S3759

Si PIN photodiode for visible to infrared photometry

S3759 is a Si PIN photodiode developed to detect and measure infrared energy emitted from YAG lasers (1.06 µm). Compared to standard Si photodiodes, S3759 delivers exceptionally high sensitivity of 0.38 A/W at 1.06 µm. The PIN structure allows high-speed response and low capacitance. The active area is as large as \$\phi\$5 mm, making optical axis alignment easier.

Features

Applications

- → High-speed response: tr=12.5 ns (VR=100 V)
- Low capacitance: Ct=10 pF (VR=100 V)
- Large active area: φ5 mm
- **■** High reliability: TO-8 metal package

- > YAG laser detection
- → Analytical equipment, etc.

Absolute maximum ratings

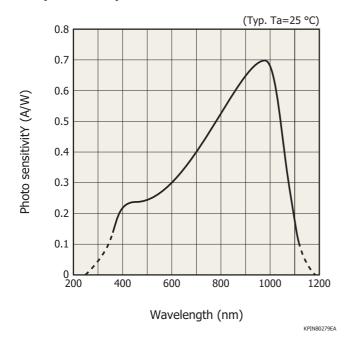
Parameter	Symbol	Value	Unit
Maximum reverse voltage	Vr max	150	V
Operating temperature	Topr	-40 to +100	°C
Storage temperature	Tstg	-55 to +125	°C

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

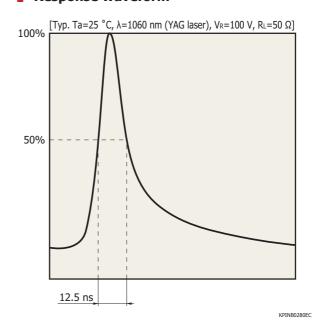
Electrical and optical characteristics (Ta=25 °C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Spectral response range	λ	- Containent	-	360 to 1120	-	nm
Peak sensitivity wavelength	λр		-	980	-	nm
Photo sensitivity	S	λ=1060 nm	0.3	0.38	-	A/W
Short circuit current	Isc	2856 K, 1000 lx	14	19	-	μΑ
Dark current	ID	VR=100 V	-	1	10	nA
Rise time	tr	λ =1060 nm, VR=100 V, RL=50 Ω	-	12.5	-	ns
Terminal capacitance	Ct	VR=100 V, f=1 MHz	-	10	-	pF

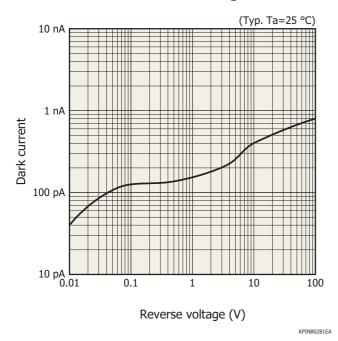
Spectral response



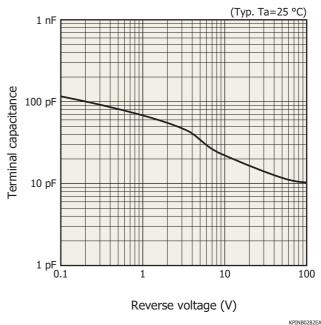
Response waveform



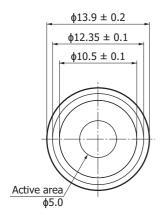
Dark current vs. reverse voltage

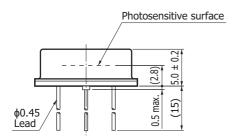


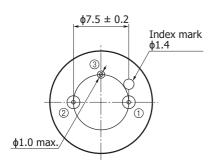
Terminal capacitance vs. reverse voltage

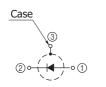


Dimensional outline (unit: mm)









Chip position accuracy with respect to the cap center X, $Y \le \pm 0.4$

KPTNA0092FA

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Related information

www.hamamatsu.com/sp/ssd/doc_en.html

- Precautions
 - · Notice
 - · Metal, ceramic, plastic packages / Precautions
- Technical information
 - · Si photodiode / Application circuit examples

Information described in this material is current as of March, 2014.

Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use.

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